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Shunt Regulator



ADE-204-029E (Z)

Rev.5 Sep. 2002

Description

The HA17L431 series and the HA17L431A series are temperature-compensated variable shunt regulators. These ICs can operate at about half voltage in comparison with HA17431 series. They can be replaced for simple Zener diode and they can also be used for switching power supply secondary-side error amplification circuit.

Features

• On-chip high-precision reference voltage source : $1.240 \text{ V} \pm 1.0\%$ at Ta = 25°C (HA17L431A)

: $1.240 \text{ V} \pm 1.5\%$ at Ta = 25° C (HA17L431)

• Small reference voltage temperature coefficient: 30 ppm/°C Typ

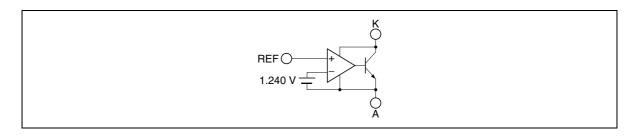
• Maximum cathode voltage: 16 V

• Maximum cathode current: 50 mA

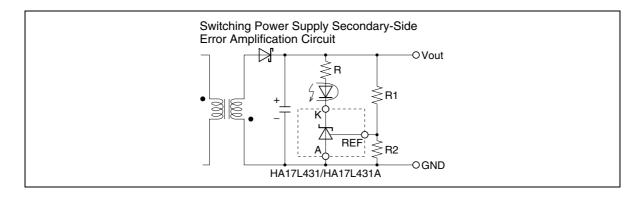
• Minimum cathode current: 200 μA Typ

• Operating temperature range: -20 to +85°C

Block Diagram



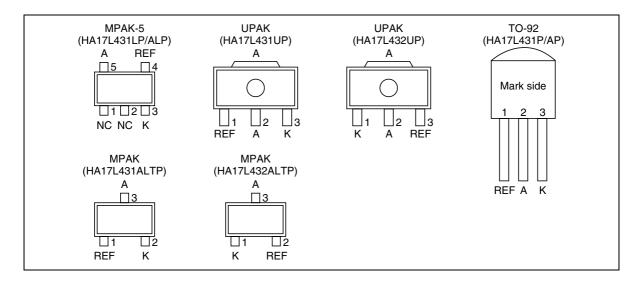
Application Circuit Example



Product Lineup

		Version			Operating Temperature	
Item		A Version Normal Ver		Package	Range	
Reference voltage	Accuracy	±1.0%	±1.5%			
(at 25°C)	Max	1.253V	1.258V	_		
	Тур	1.240V	1.240V	_		
	Min	1.227V	1.222V	_		
Industrial use		HA17L431ALTP		MPAK	−20 to +85°C	
		HA17L432ALTP		_		
		HA17L431ALP		MPAK-5	_	
			HA17L431LP	_		
			HA17L431UP	UPAK	_	
			HA17L432UP	_		
		HA17L431AP		TO-92	_	
			HA17L431P	_		

Pin Arrangement



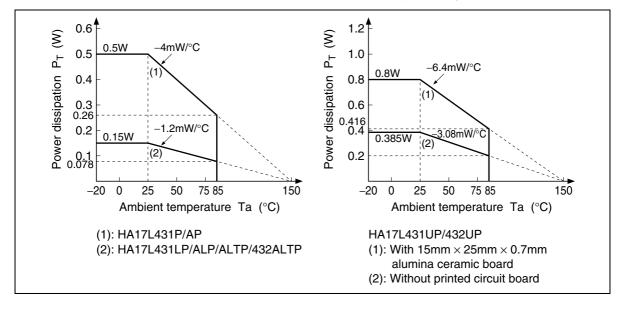
Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

		Rated Value					
Item	Symbol	HA17L431LP/ HA17L431ALP	HA17L431P/ HA17L431AP	HA17L431UP/ HA17L432UP	HA17L431ALTP/ HA17L432ALTP	Unit	Note
Cathode voltage	V_{KA}	16	16	16	16	V	1
Continuous cathode current	I _K	-30 to +50	-30 to +50	-30 to +50	-30 to +50	mA	
Reference input current	Iref	-0.05 to +5	-0.05 to +5	-0.05 to +5	-0.05 to +5	mA	
Power dissipation	P _T	150	500	800	150	mW	2
Operating temperature	Topr	-20 to +85	–20 to +85	-20 to +85	–20 to +85	°C	
Storage temperature	Tstg	-55 to +150	-55 to +150	-55 to +150	-55 to +150	°C	

Notes: 1. The anode pin is used as the reference for voltage values.

2. These values apply when $Ta \le 25^{\circ}C$. If $Ta \ge 25^{\circ}C$, derate by below figure.

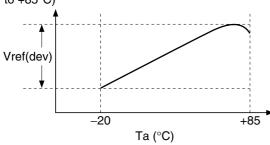


Electrical Characteristics

 $(Ta = 25^{\circ}C, I_{K} = 10 \text{ mA})$

Item	Symbol	Min	Тур	Max	Unit	Test Condition	Remark		
Reference voltage	Vref	1.222	1.240	1.258	V	V _{KA} = Vref	HA17L431		
		1.227	1.240	1.253	-		HA17L431A		
Reference voltage deviation	Vref(dev)	_	5	_	mV	$V_{KA} = Vref,$ $Ta = -20^{\circ}C \text{ to } +85^{\circ}C$	*1		
Reference voltage temperature coefficient	∆Vref/∆Ta	_	±30	_	ppm/°C	V _{KA} = Vref, 0°C to 50°C gradient			
Reference voltage regulation	$\Delta V ref / \Delta V_{_{KA}}$	_	1.0	2.0	mV/V	V _{KA} = Vref to 16V			
Reference input current	Iref	_	2	6	μА	R1 = 10 kΩ, R2 = ∞			
Reference current temperature deviation	Iref(dev)	_	0.5	_	μΑ	R1 = 10 k Ω , R2 = ∞ , Ta = -20°C to +85°C			
Minimum cathode current	lmin	_	0.2	1.0	mA	V _{KA} = Vref	*2		
Off cathode current	loff	_	0.001	1.0	μА	V _{KA} = 16 V, Vref = 0 V			
Dynamic impedance	Z _{KA}	_	0.2	0.5	Ω	$V_{KA} = Vref,$ $I_{K} = 1 \text{ mA to } 50 \text{ mA}$			

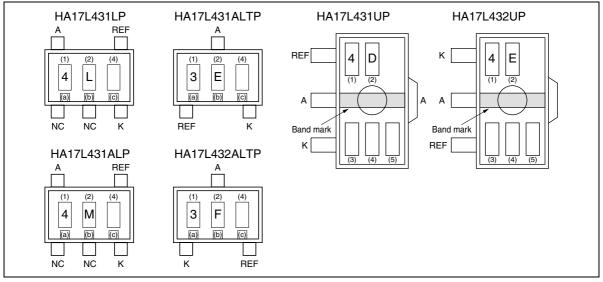
Notes: 1. Vref(dev) = (Vref maximum value at $Ta = -20^{\circ}C$ to $+85^{\circ}C$) – (Vref minimum value at $Ta = -20^{\circ}C$ to $+85^{\circ}C$)



2. Definition of minimum cathode current. Imin is the cathode current value at which $Vref = Vref_{(IK = 10 \, mA)} - 15 \, mV$.

MPAK-5(5-pin), MPAK(3-pin) and UPAK Marking Patterns

The marking patterns shown below are used on MPAK-5, MPAK and UPAK products. Note that the product code and mark pattern are different. The pattern is laser-printed.



Notes: 1. Boxes (1) to (5) in the figures show the position of the letters or numerals, and are not actually marked on the package.

2. The letters (1) and (2) show the product specific mark pattern.

Product	(1)	(2)
HA17L431LP	4	L
HA17L431ALP	4	M
HA17L431ALTP	3	E
HA17L432ALTP	3	F
HA17L431UP	4	D
HA17L432UP	4	E

- 3. The letter (3) shows the production year code (the last digit of the year) for UPAK products.
- 4. The bars (a), (b) and (c) show a production year code for MPAK-5 and MPAK products as shown below. After 2010 the code is repeated every 8 years.

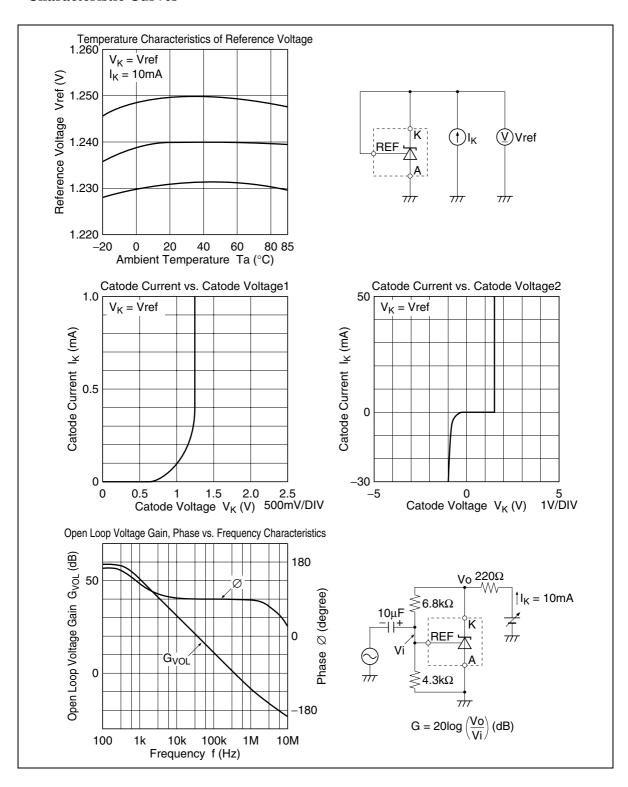
Year	2002	2003	2004	2005	2006	2007	2008	2009
(a)	None	None	None	Bar	Bar	Bar	Bar	None
(b)	None	Bar	Bar	None	None	Bar	Bar	None
(c)	Bar	None	Bar	None	Bar	None	Bar	None

5. The letter (4) shows the production month code (see table below).

Production month	Jan.	Feb.	Mar.	Apr.	May.	Jun.	Jul.	Aug.	Sep.	Oct.	Nov.	Dec.
Marked code	Α	В	С	D	Е	F	G	Н	J	K	L	М

6. The letter (5) shows manufacturing code. For UPAK products.

Characteristic Curves



Noise Recovery Characteristics of HA17L431A and HA17L431

The HA17L431A bettered V_{KA} and Vref recovery time against the HA17L431 when it was inputted noise.

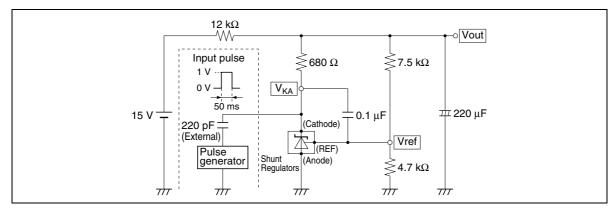


Figure 1 Noise Response Characteristics Measurement Circuit

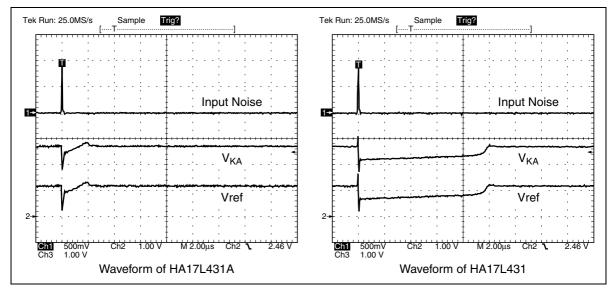
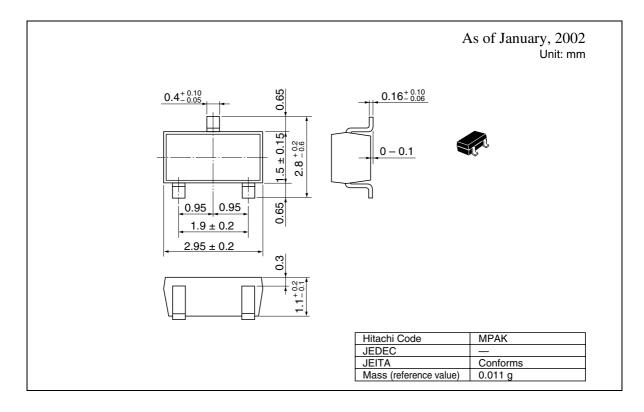
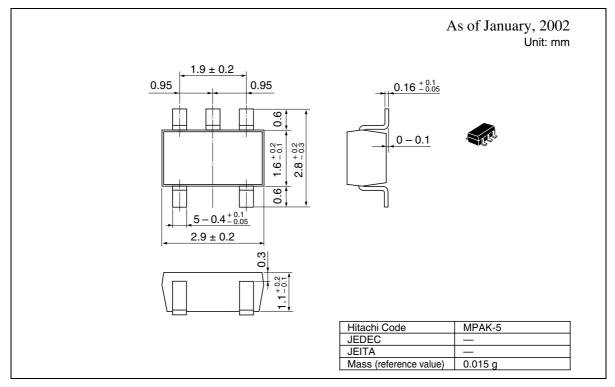
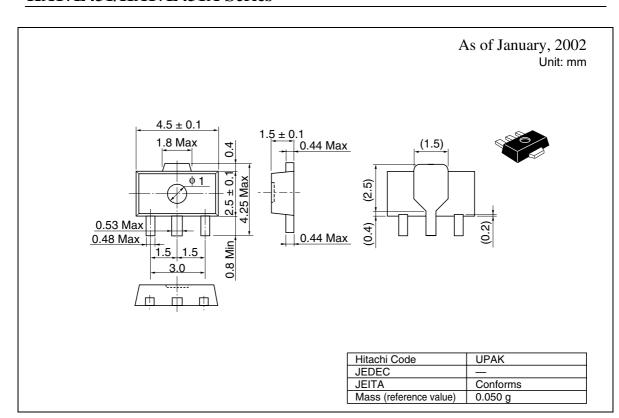


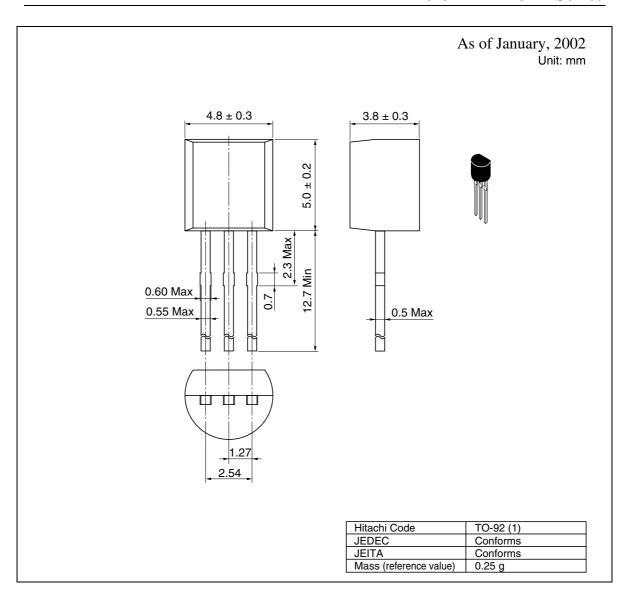
Figure 2 Noise Recovery Characteristics

Package Dimension









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